



40V MATCHED PAIR PNP SMALL SIGNAL TRANSISTOR IN SOT363

#### **Features**

- BV<sub>CEO</sub> > -40V
- I<sub>C</sub> = -200mA High Collector Current
- Pair of PNP Transistors That Are Intrinsically Matched (Note 1)
- 2% Matching on Current Gain (h<sub>FE</sub>)
- 2mV Matching on Base-Emitter Voltage (V<sub>BE</sub>)
- Fully Internally Isolated in a Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 2 & 3)
- Halogen and Antimony Free. "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 5)

#### **Mechanical Data**

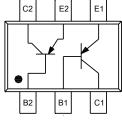
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

#### **Applications**

- Current Mirrors
- Differential and Instrumentation Amplifiers
- Comparators



Top View



Device Schematic and Pin-Out Top View

### Ordering Information (Notes 5 & 6)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DMMT3906W-7-F	AEC-Q101	K4B	7	8	3,000
DMMT3906WQ-7-F	Automotive	K4B	7	8	3,000

Notes:

1. Intrinsically matched pair as this is built with adjacent die from the same wafer.

2. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

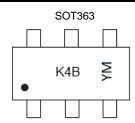
3. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

4. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

5. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

6. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



K4B = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 2 = February)

Date Code Key

Date Code Rey									1			
Year	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	E	F	G	Н		J	К	L	М	Ν	0	Р
Month	Jan	Feb	Mar	Apr	Мау	Ju	n J	ul Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6		7 8	9	0	N	D



#### Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	V
Collector Current	lc	-200	mA

# Thermal Characteristics – Total Device (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 7) Total Device	PD	200	mW	
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>θJA</sub>	625	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

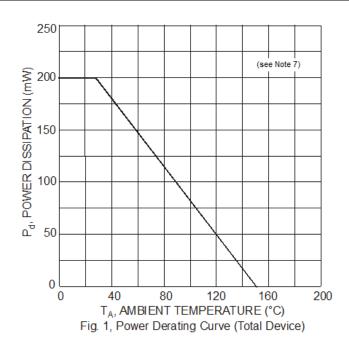
#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 7. For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state.

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

# **Thermal Characteristics – Total Device**





### Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Min	TYP	Max	Unit	Test Condition
OFF CHARACTERISTICS				•	•	•
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	_	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-40	_	_	V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5.0	_	_	V	$I_{\rm E} = -100 \mu A, I_{\rm C} = 0$
Collector Cutoff Current	ICEX	_	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = 3.0V$
Base Cutoff Current	I <sub>BL</sub>	_	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 9)					•	·
DC Current Gain	hfe	60 80 100 60 30	_	 300 		$\label{eq:linear} \begin{array}{llllllllllllllllllllllllllllllllllll$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		_	-250 -400	mV	$I_{C} = -10mA$ , $I_{B} = -1.0mA$ $I_{C} = -50mA$ , $I_{B} = -5.0mA$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.65	—	-850 -950	mV	$I_{C} = -10mA$ , $I_{B} = -1.0mA$ $I_{C} = -50mA$ , $I_{B} = -5.0mA$
MATCHING CHARACTERISTICS					1	
DC Current Gain Matching (Note 10)	$h_{FE1} / h_{FE2}$	—	1	2	%	$I_{C} = -2mA, V_{CE} = -5V$
Base-Emitter Voltage Matching (Note 11)	V <sub>BE1</sub> - V <sub>BE2</sub>		1	2	mV	$I_C = -2mA$ , $V_{CE} = -5V$
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(SAT)1</sub> / V <sub>CE(SAT)2</sub>	—	1	2	%	$I_{C} = -10mA, I_{B} = -1.0mA$
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(SAT)1</sub> / V <sub>BE(SAT)2</sub>	_	1	2	%	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA
SMALL SIGNAL CHARACTERISTICS					•	·
Output Capacitance	C <sub>OBO</sub>	_	—	4.5	pF	$V_{CB} = -5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance	C <sub>IBO</sub>	_	—	10.0	pF	$V_{EB} = -0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	h <sub>IE</sub>	2.0	—	12	kΩ	
Voltage Feedback Ratio	h <sub>RE</sub>	0.1	—	10	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h <sub>FE</sub>	100	—	400	_	f = 1.0kHz
Output Admittance	hOE	3.0	—	60	μS	
Current Gain-Bandwidth Product	f⊤	250	_	_	MHz	$V_{CE} = -20V, I_C = -10mA, f = 100MHz$
Noise Figure	NF	_	_	4.0	dB	$V_{CE} = -5.0V, I_C = -100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS						
Delay Time	t <sub>D</sub>	_	—	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Rise Time	t <sub>R</sub>	_		35	ns	$V_{BE(OFF)} = 0.5V, I_{B1} = -1.0mA$
Storage Time	ts			225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Fall Time	tF			75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$

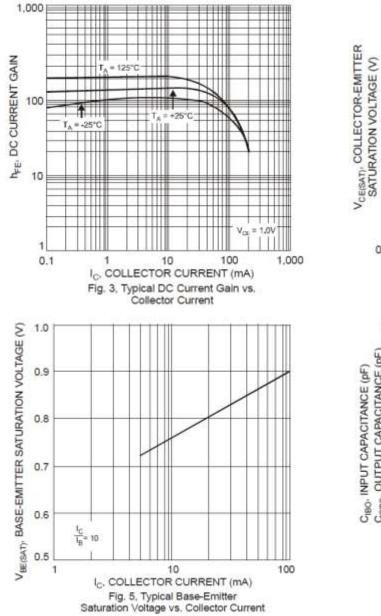
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

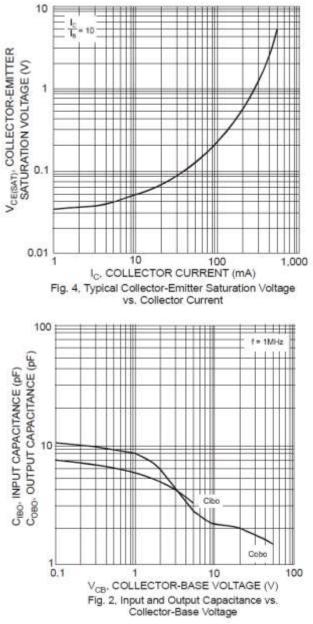
10. Is the ratio of one transistor compared to the other transistor.

11.  $V_{BE1}$  -  $V_{BE2}$  is the absolute difference of one transistor compared to the other transistor.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

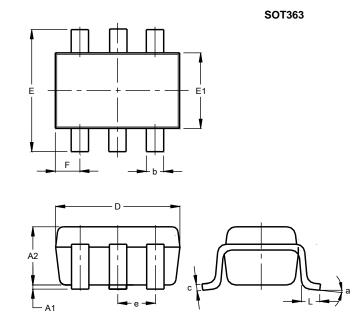






# **Package Outline Dimensions**

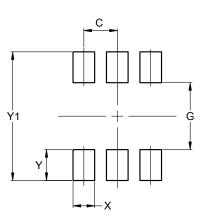
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363								
Dim	Min Max Typ							
A1	0.00	0.10	0.05					
A2	0.90	1.00	1.00					
b	0.10	0.30	0.25					
С	0.10 0.22 0.11							
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	).650 B	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



 
 Dimensions
 Value (in mm)

 C
 0.650

 G
 1.300

 X
 0.420

 Y
 0.600

 Y1
 2.500

SOT363



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